NSN 5961-01-325-2858

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-325-2858 **Inclosure Material:** Glass or plastic **Overall Length:** Between 0.130 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.092 inches and 0.130 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 125.0 working peak reverse voltage **Current Rating Per Characteristic:** 4.00 amperes forward current, average preset and 150.00 milliamperes collector current, dc absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No